



Quality Comparison of SLC, MLC and eMLC.

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Agenda

- The features of SLC, MLC and eMLC.
 - Read, Write and Erase Time
- Read Bit Error VS P/E Cycle.
- Program/Erase Error VS P/E Cycle
- Bit Error with Power Cycling



SLC, MLC, eMLC

	Read Page	Program Page	Erase Block	P/E Cycle	ECC
SLC(5xnm) A	25us	200us	1.5ms	100,000	1Bit/512
SLC(4xnm) A	25us	250us	2ms	100,000	1Bit/512
SLC(3xnm) A	50us	500us	1.5ms	100,000	24Bits/1K
SLC(3xnm)	25us	230us	0.7ms	100,000	4Bit/512
SLC(2xnm)	35us	300us	0.7	100,000	8Bit/512
MLC(3xnm)	50us	900us	3ms	5,000	24Bits/1K
MLC(2xnm)	75us	1300	4ms	3,000	24Bits/1K
eMLC (3xnm)	50us	1600us	5.5ms	30,000	24Bits/1K

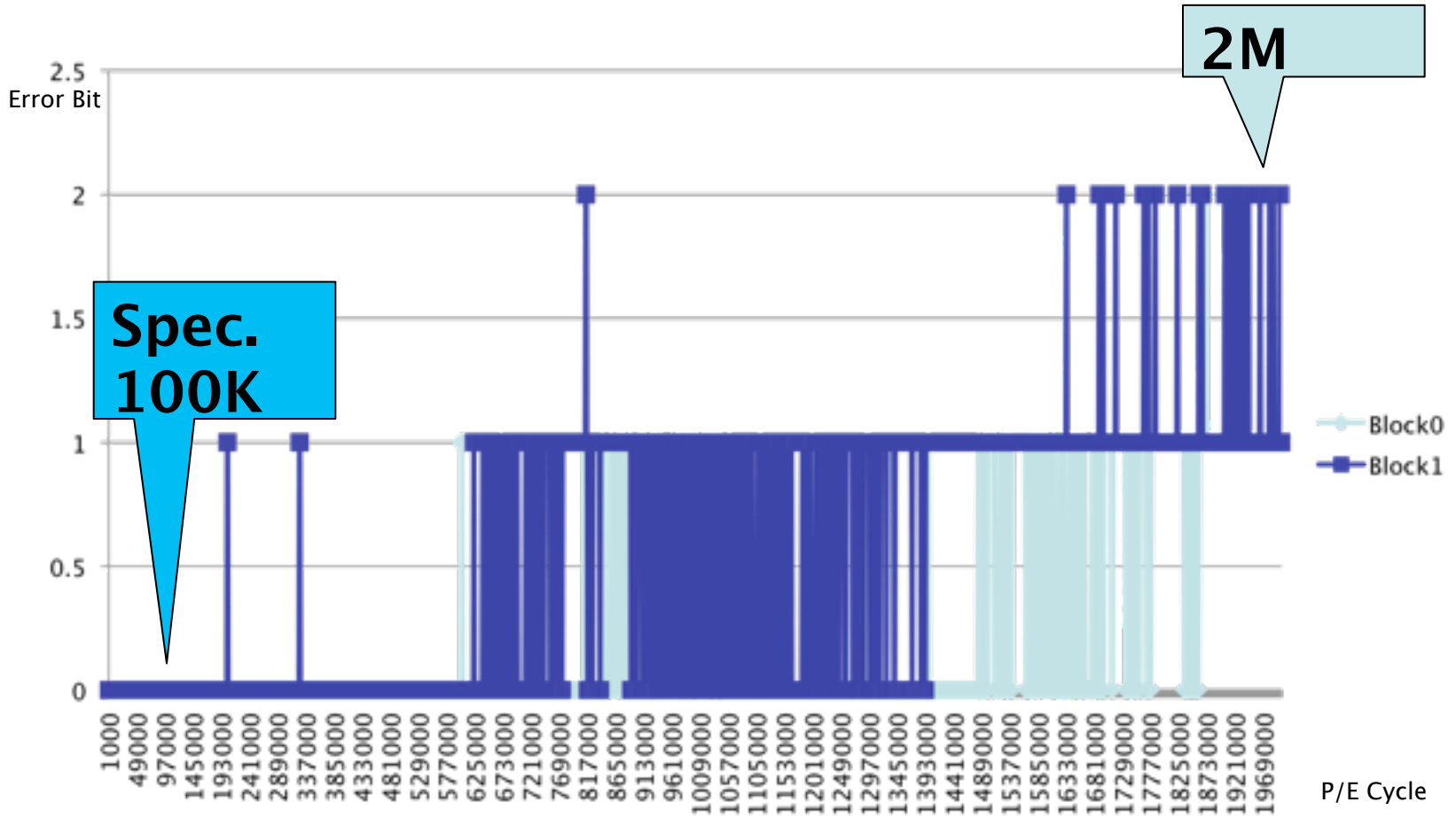
Fl
Sa

Flash test condition

- Test 2 to 5 blocks of each flash chip.
- The testing sample is not enough to approve flash quality.
- We just make comparison for different process of flash chip, but not going say the flash chip has such good quality according this report.
- 1K BCH16/24 ECC Engine for testing

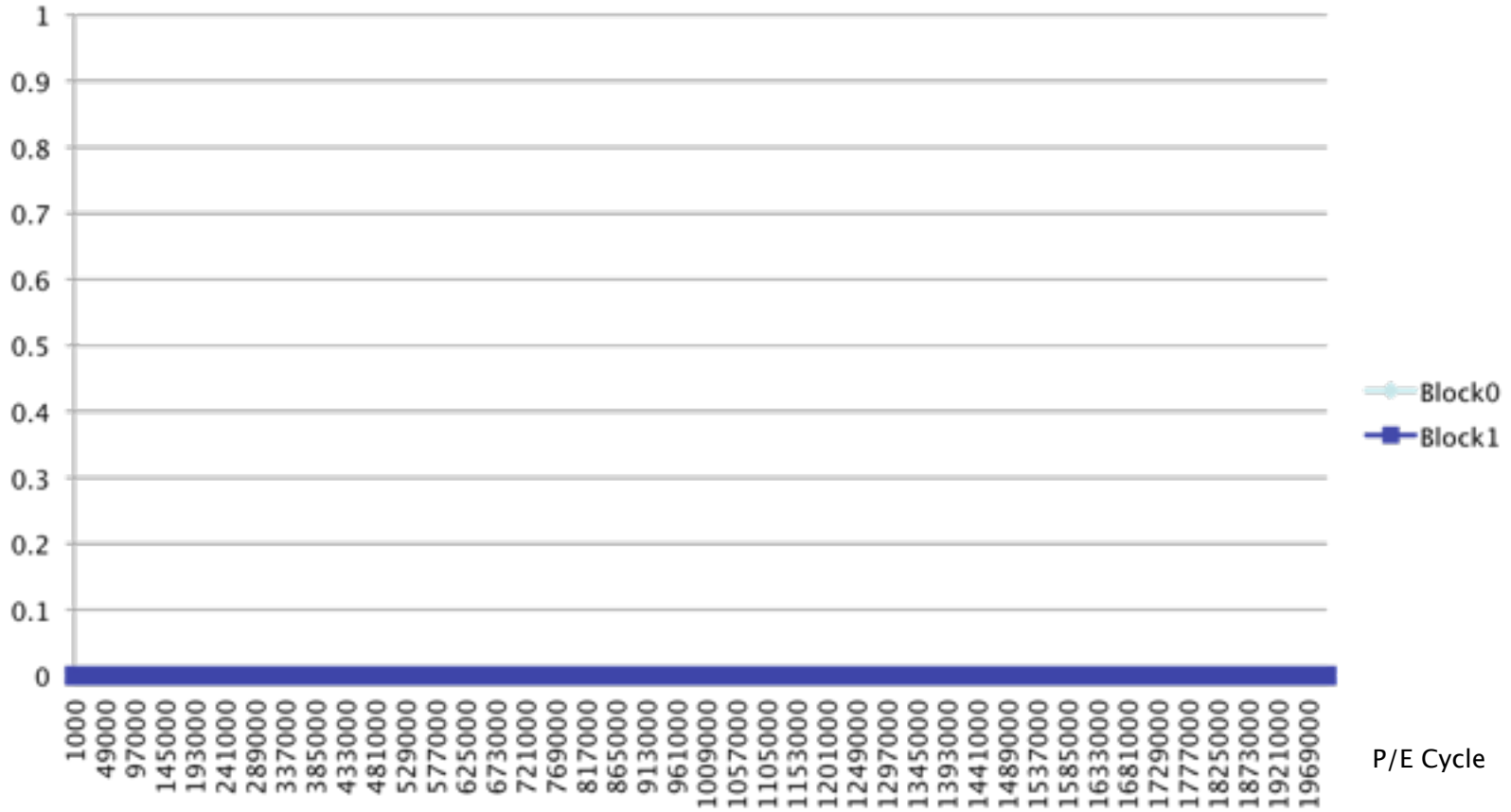


Bit Error VS P/E Cycle 5xnm SLC(Brand A)



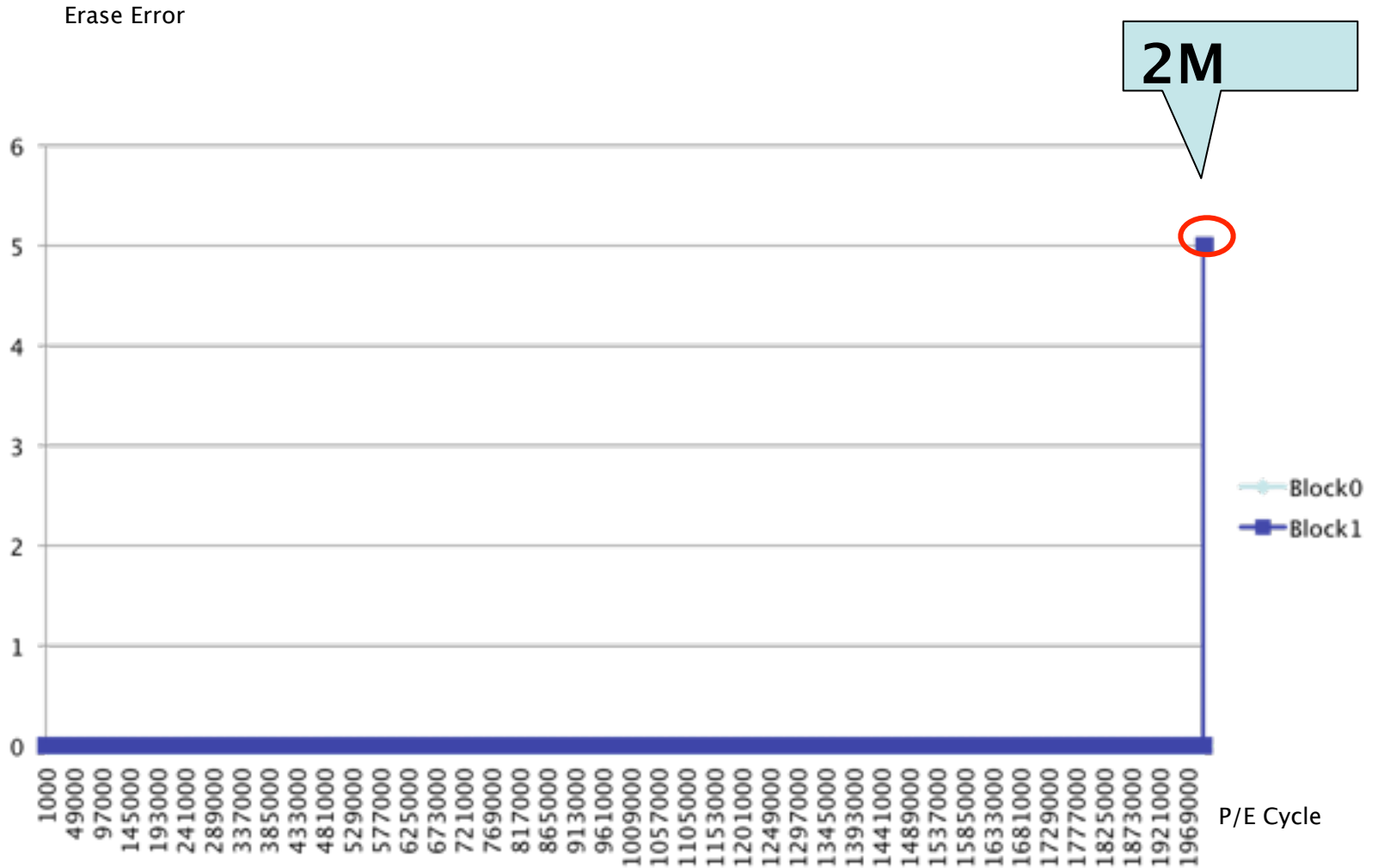


Program Error VS P/E Cycle 5xnm SLC(Brand A)





Erase Error VS P/E Cycle 5xnm SLC(Brand A)

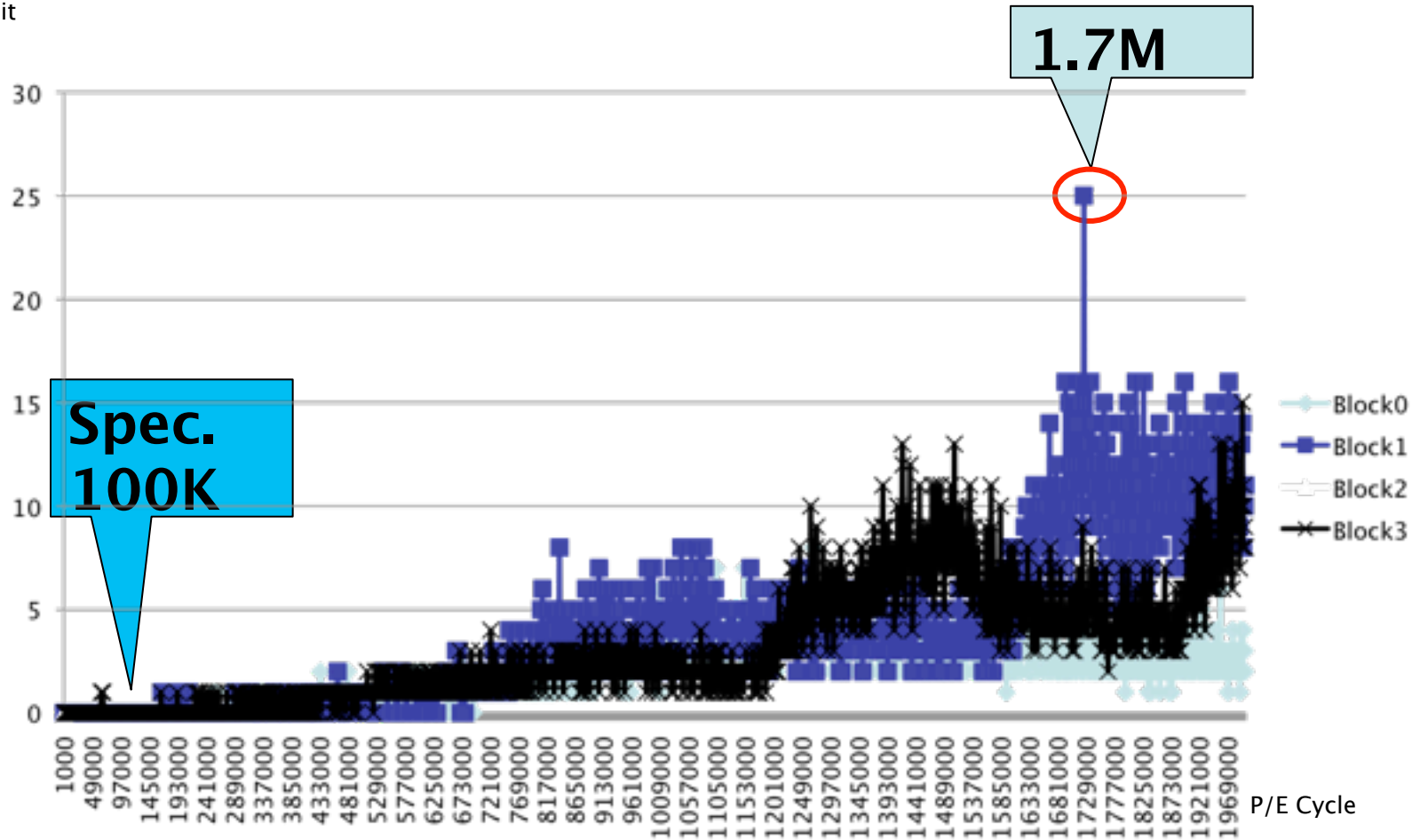


Flash Memory Summit 2011
Santa Clara, CA



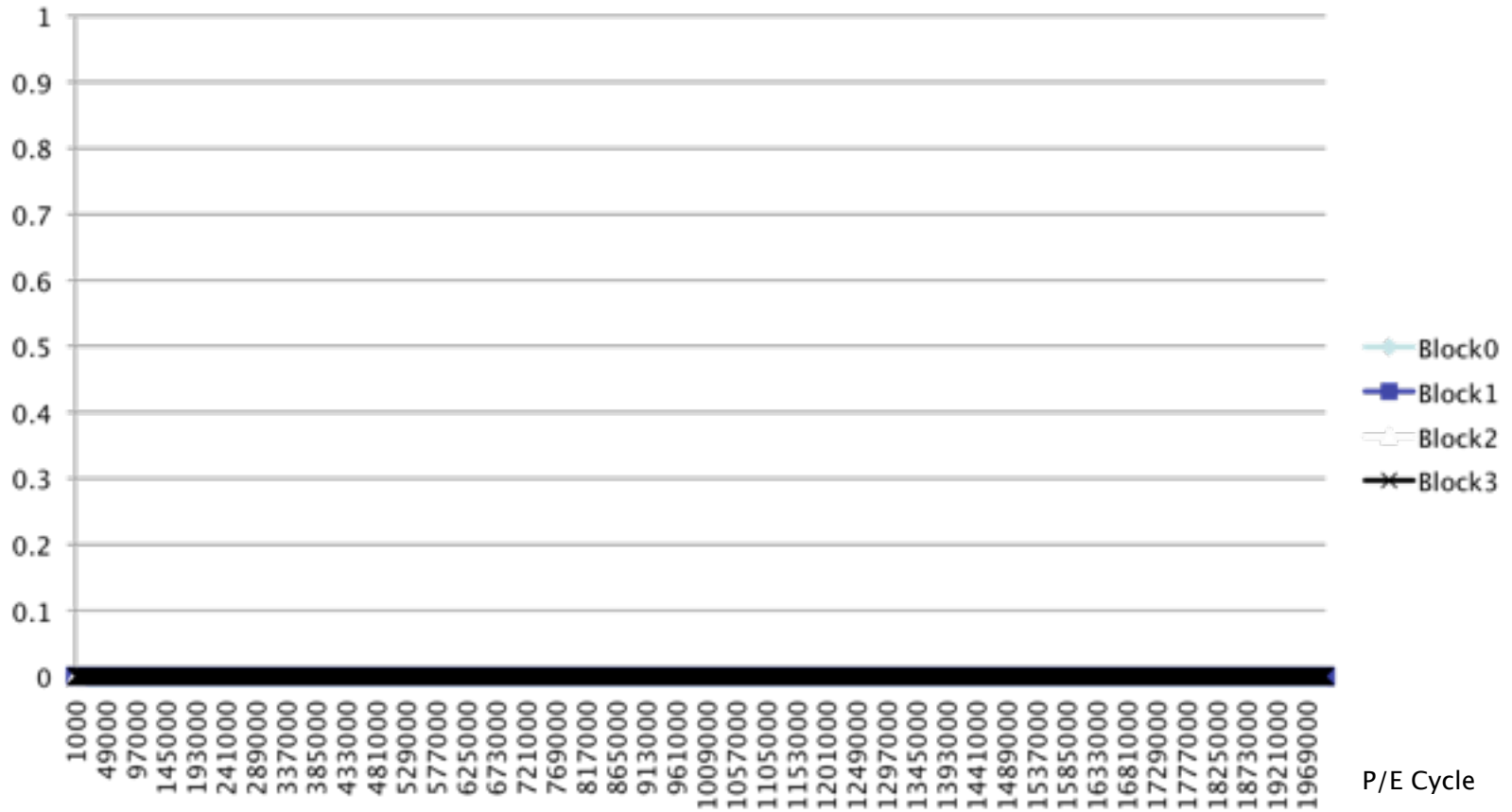
Bit Error VS P/E Cycle 4xnm SLC(Brand A)

Error Bit



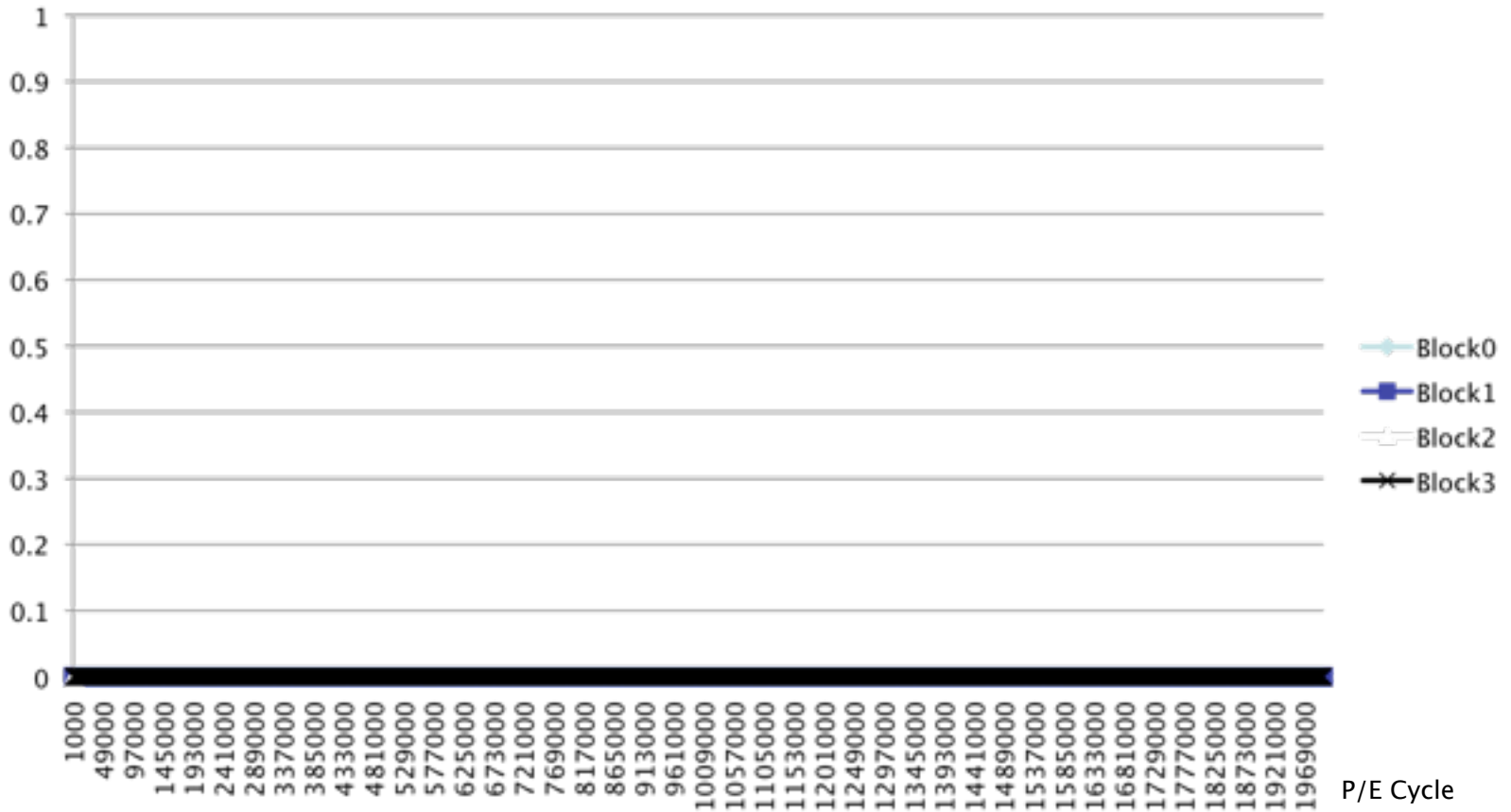


Program Error VS P/E Cycle 4xnm SLC(Brand A)



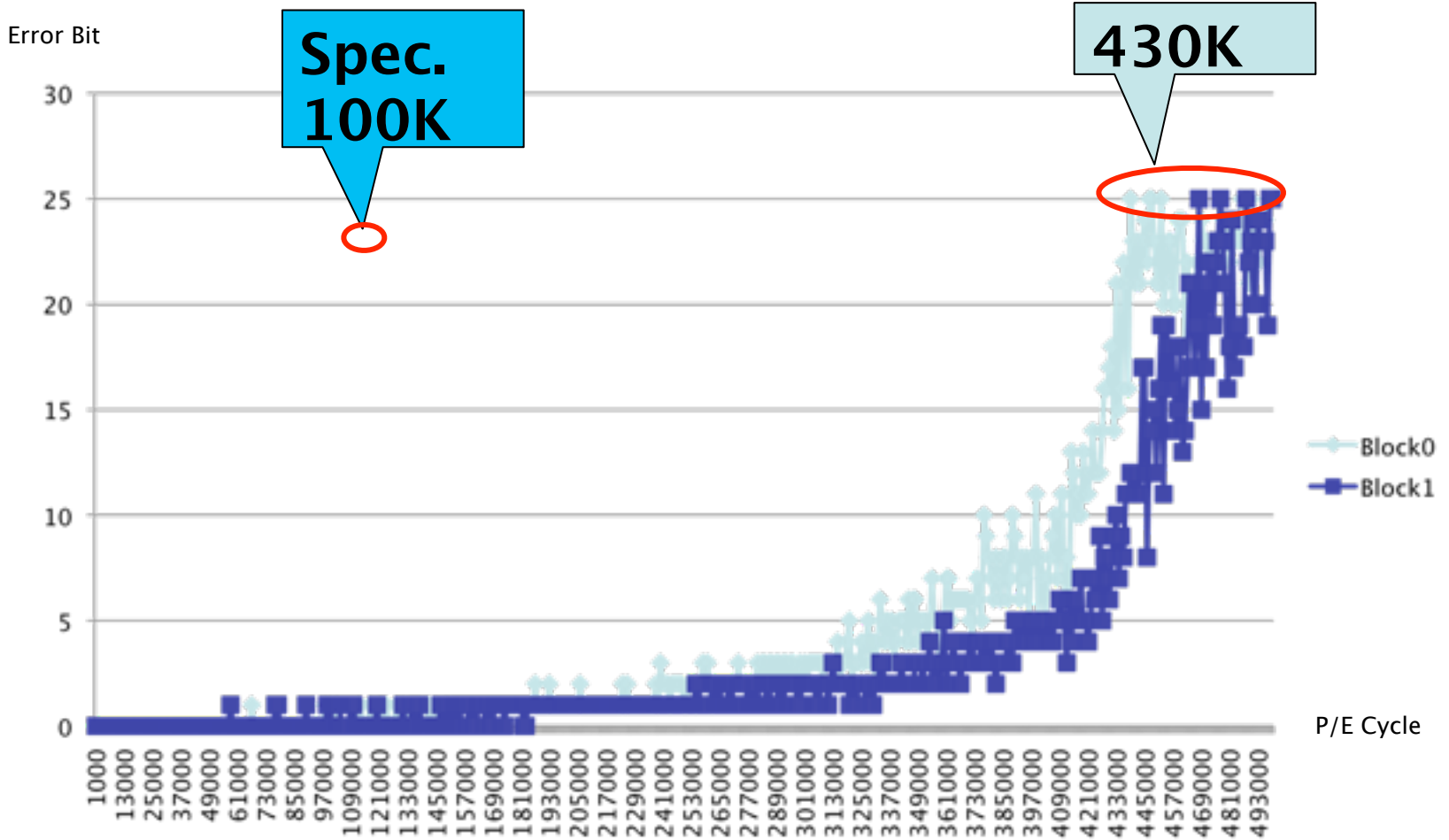


Erase Error VS P/E Cycle 4xnm SLC(Brand A)



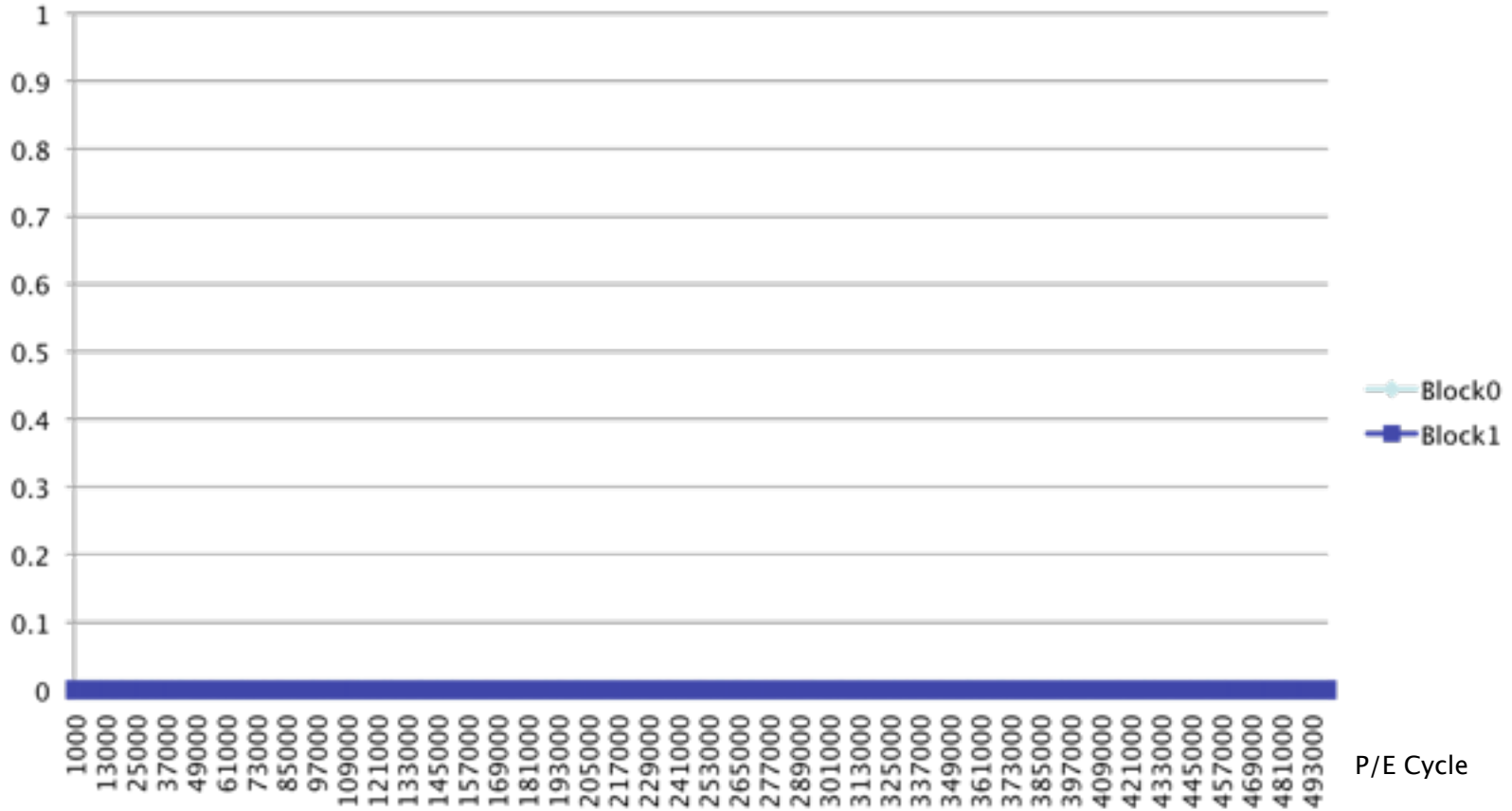


Bit Error VS P/E Cycle 3xnm SLC(Brand A)



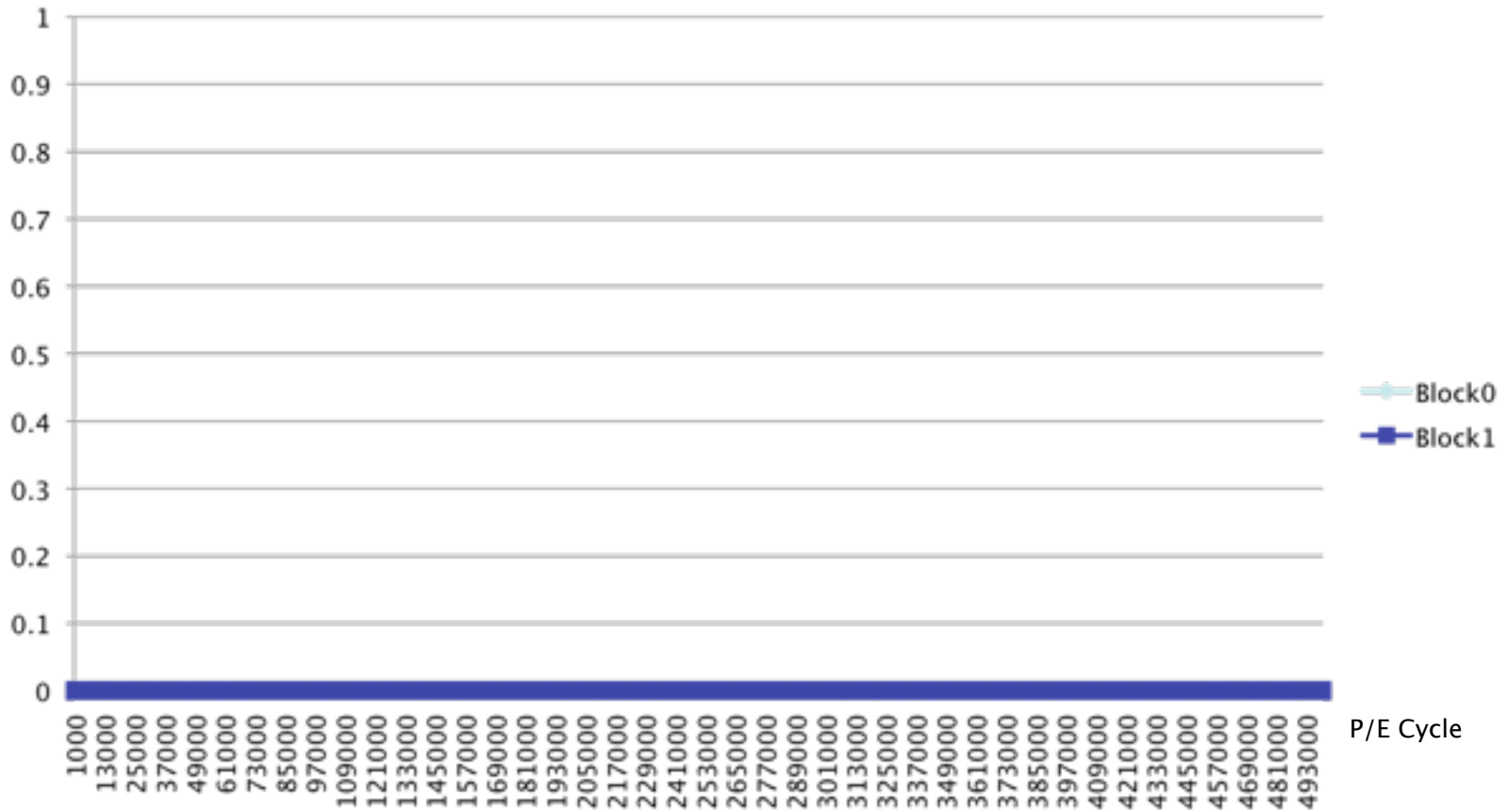


Program Error VS P/E Cycle 3xnm SLC(Brand A)



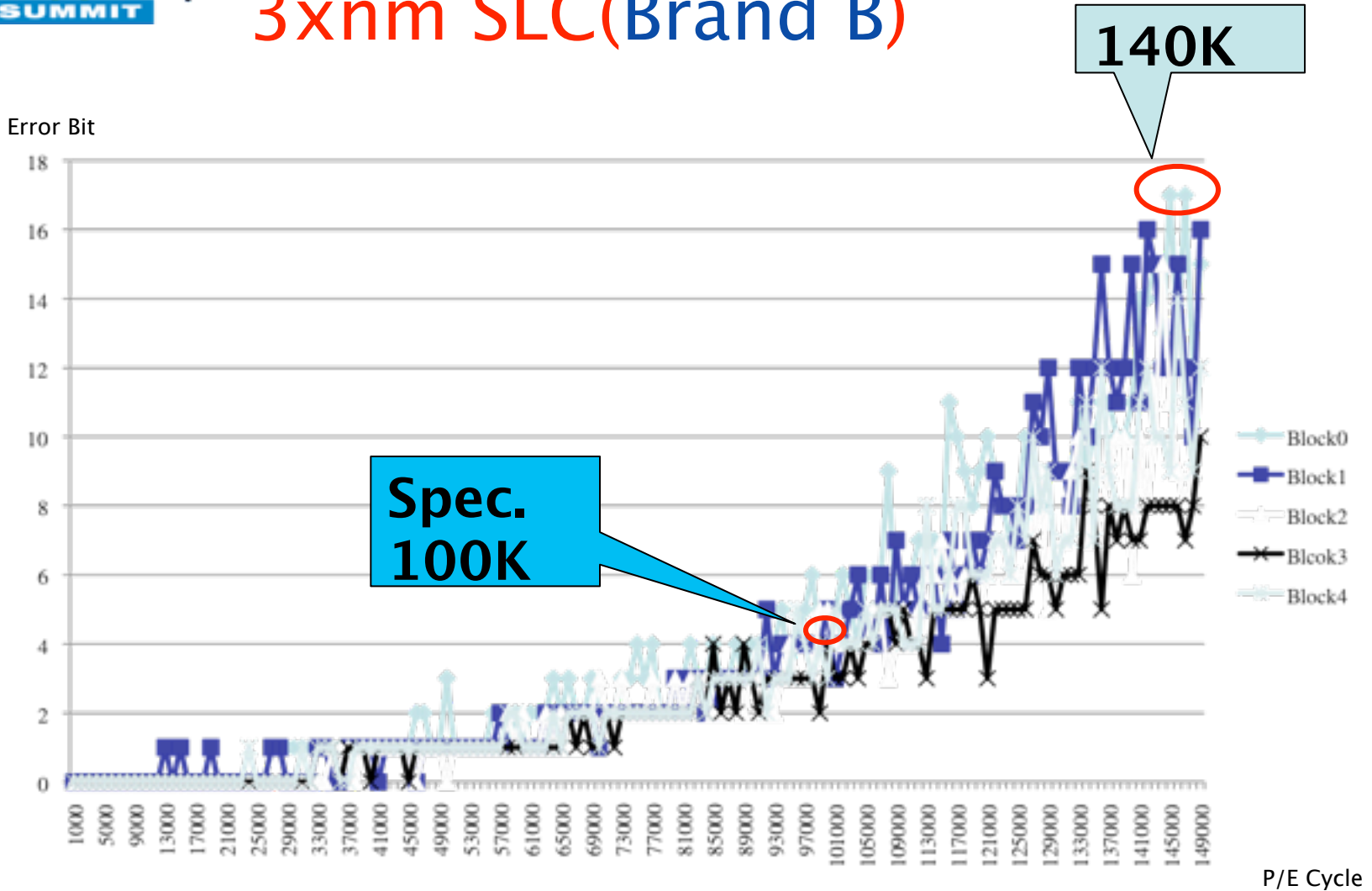


Erase Error VS P/E Cycle 3xnm SLC(Brand A)



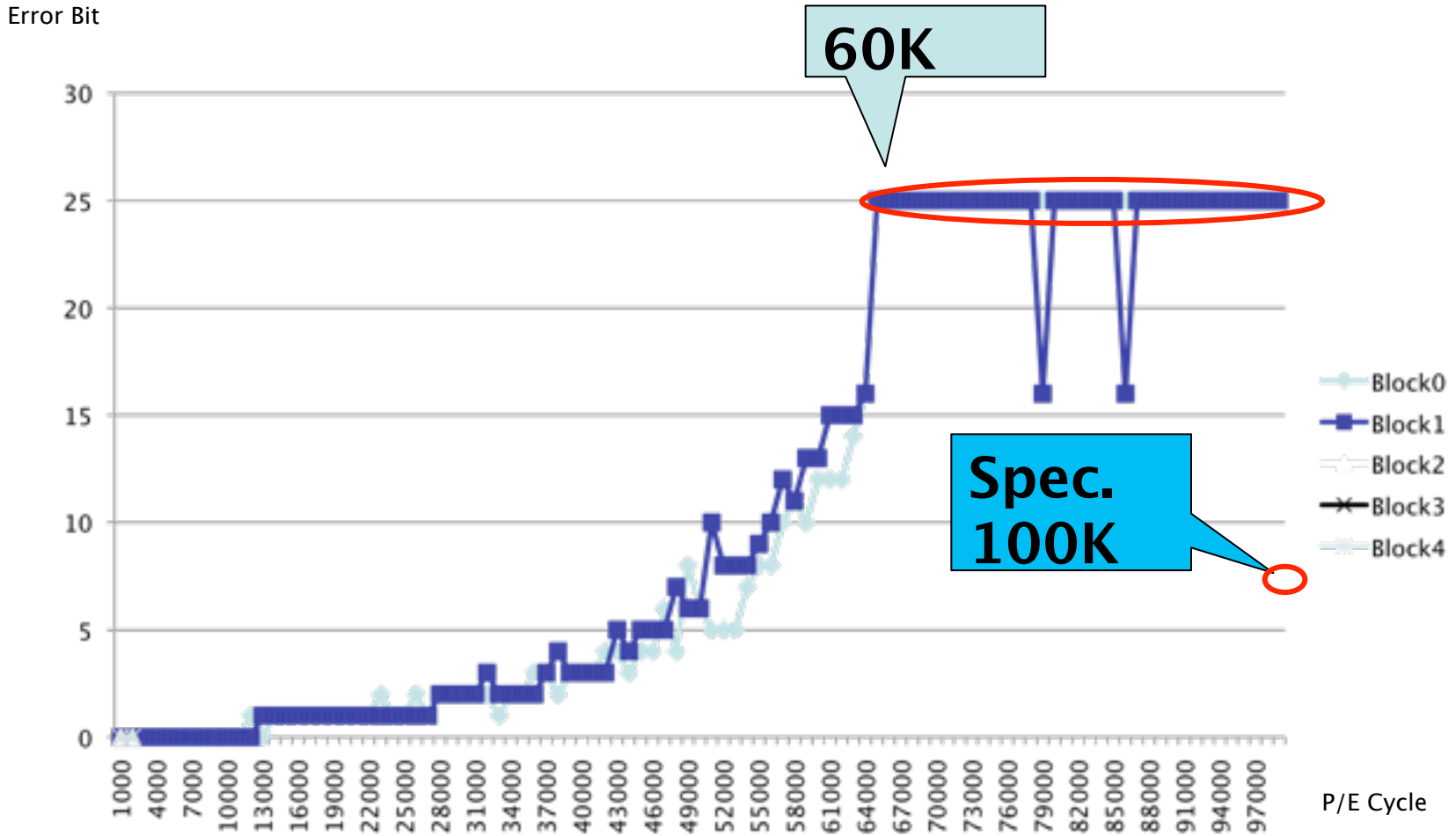


Bit Error VS P/E Cycle 3xnm SLC(Brand B)



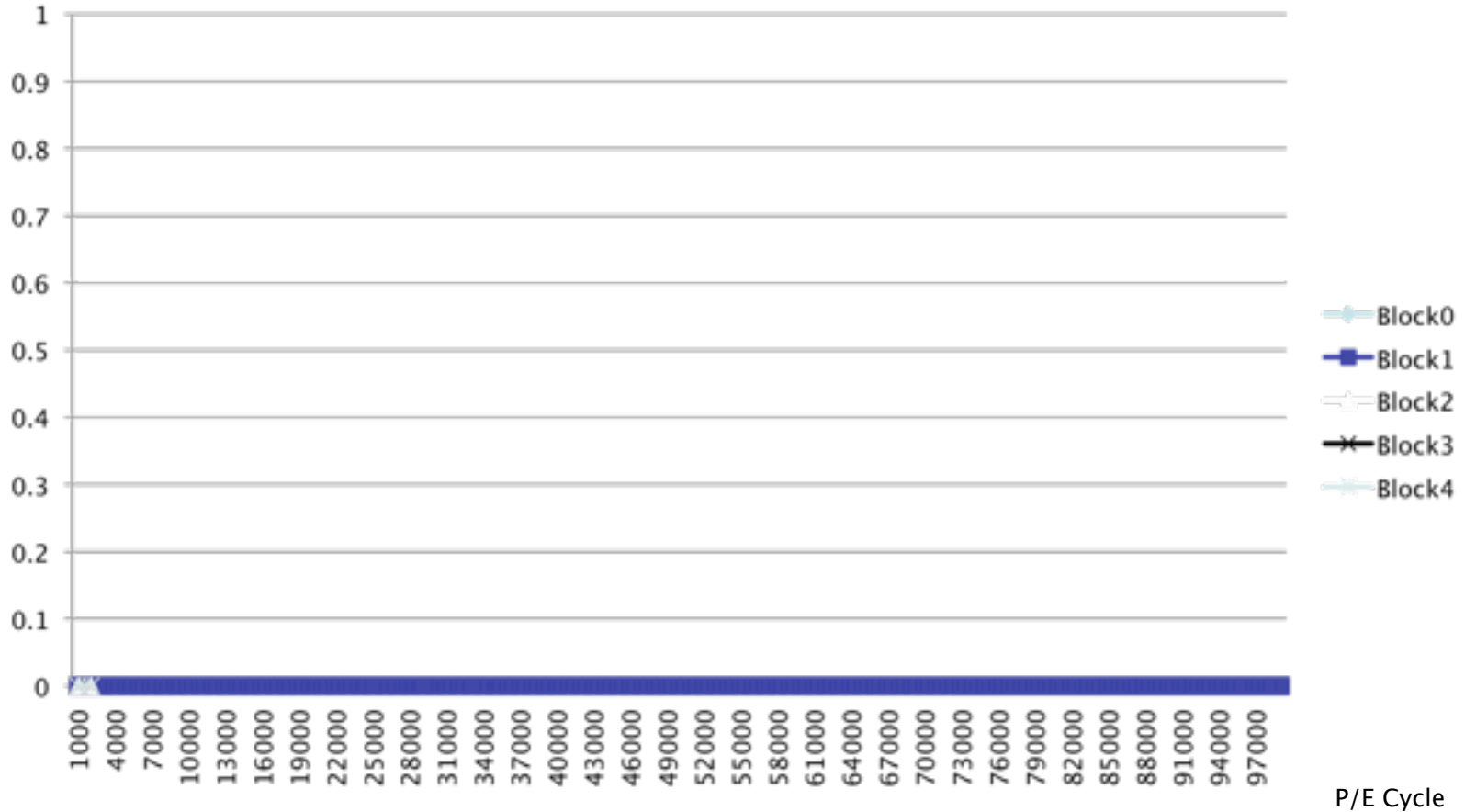


Bit Error VS P/E Cycle 2xnm SLC(Brand B)



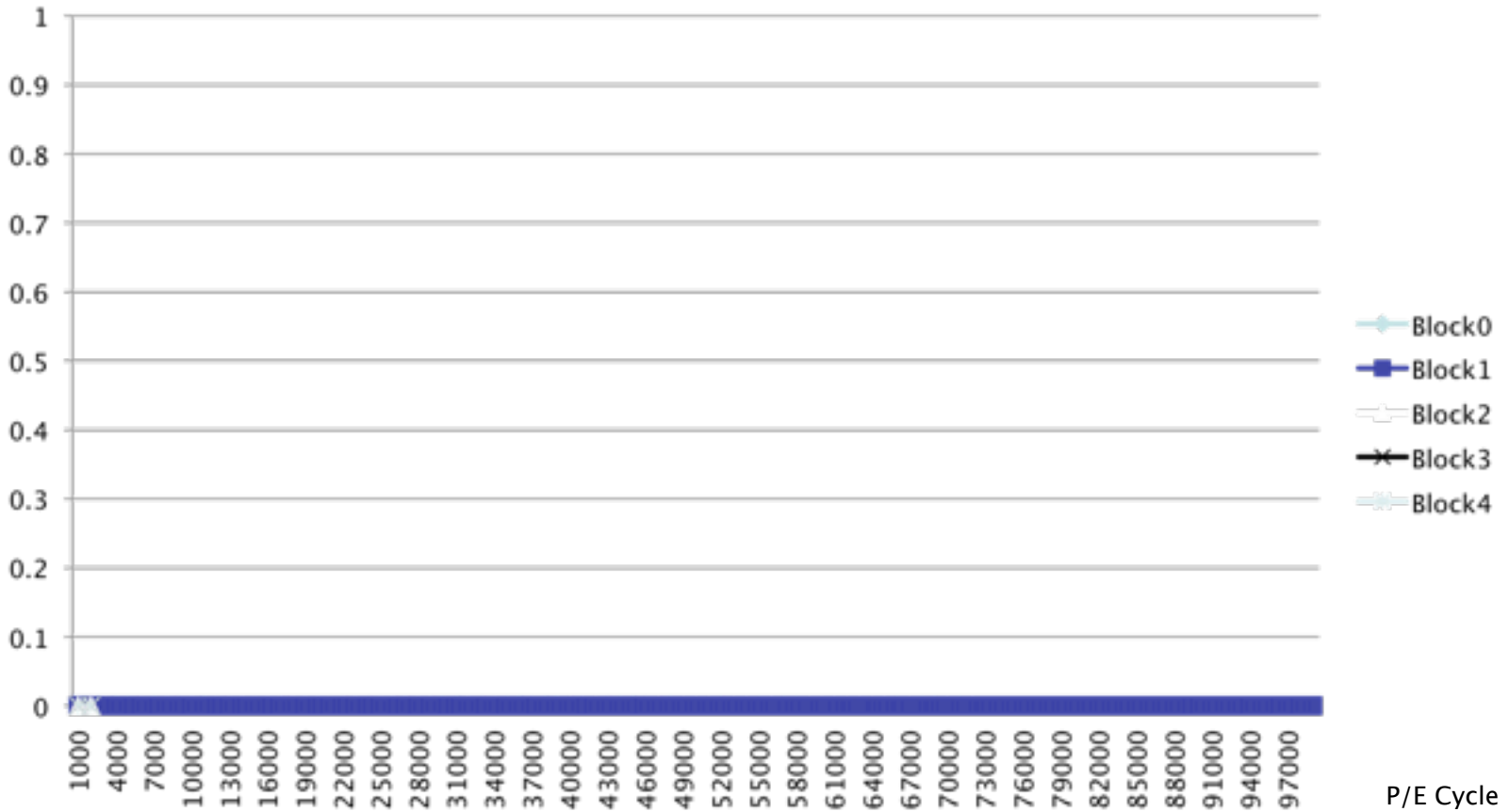


Program Error VS P/E Cycle 2xnm SLC(Brand B)

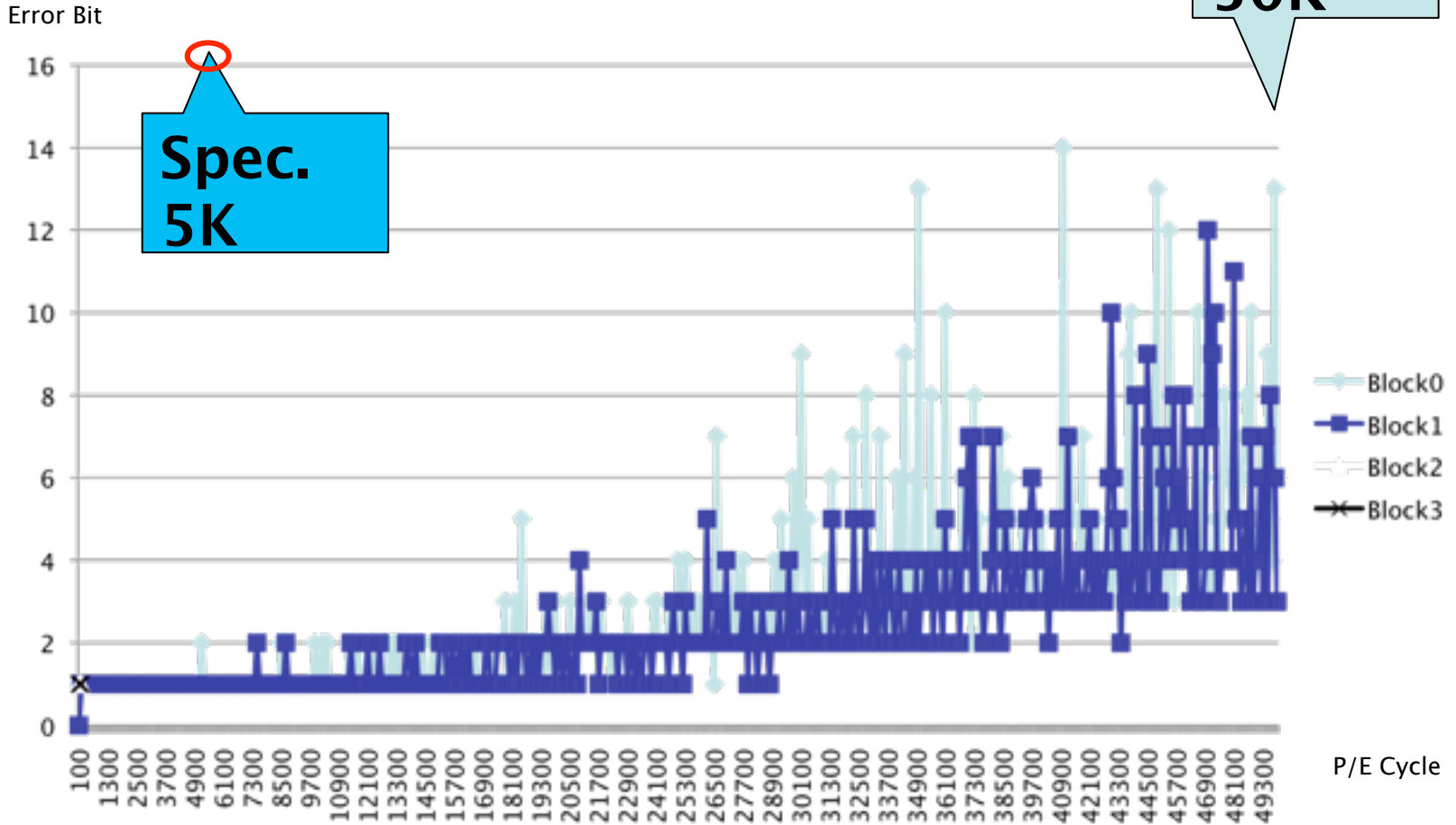




Erase Error VS P/E Cycle 2xnm SLC(Brand B)

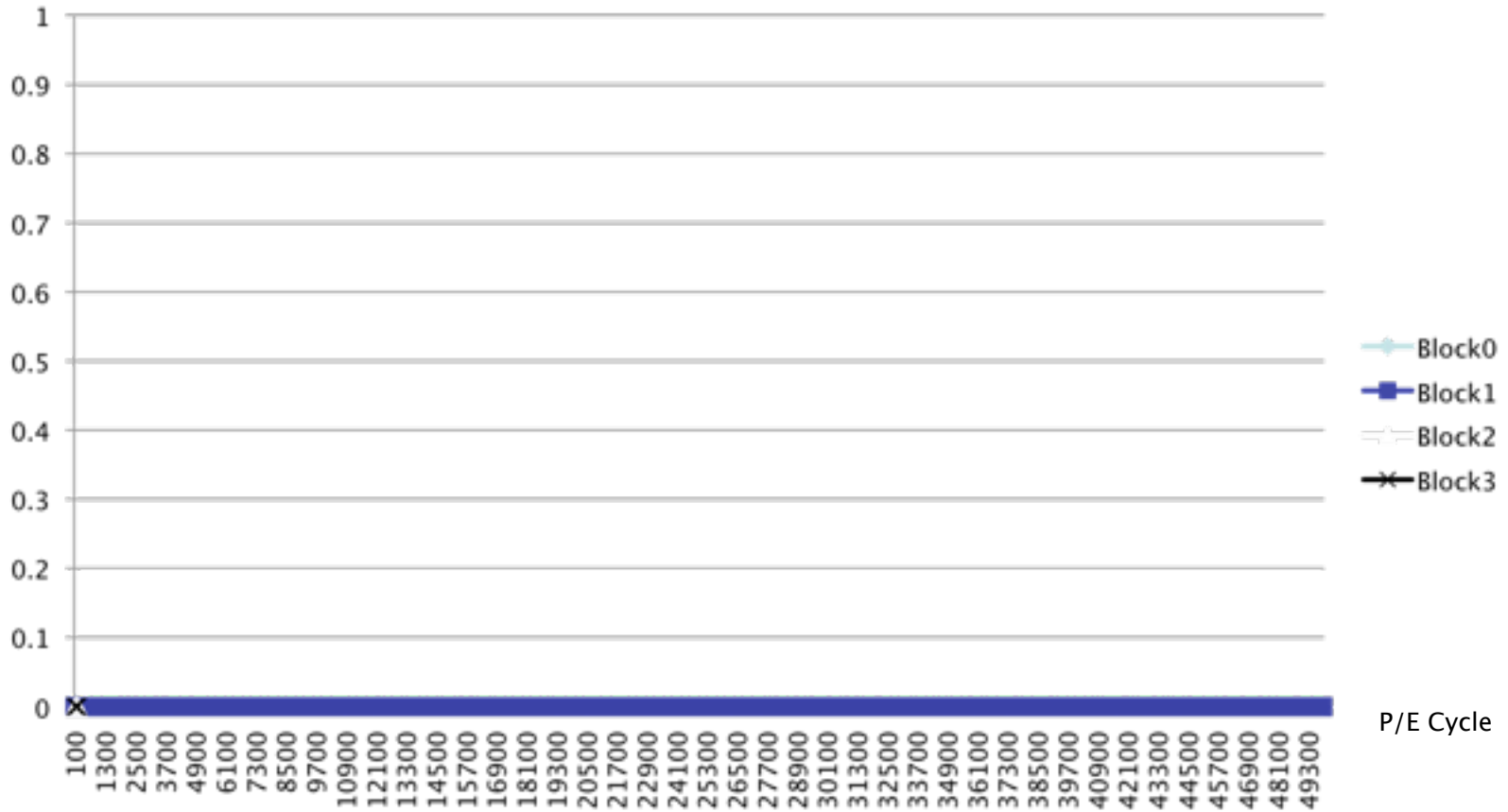


Bit Error VS P/E Cycle 3xnm MLC



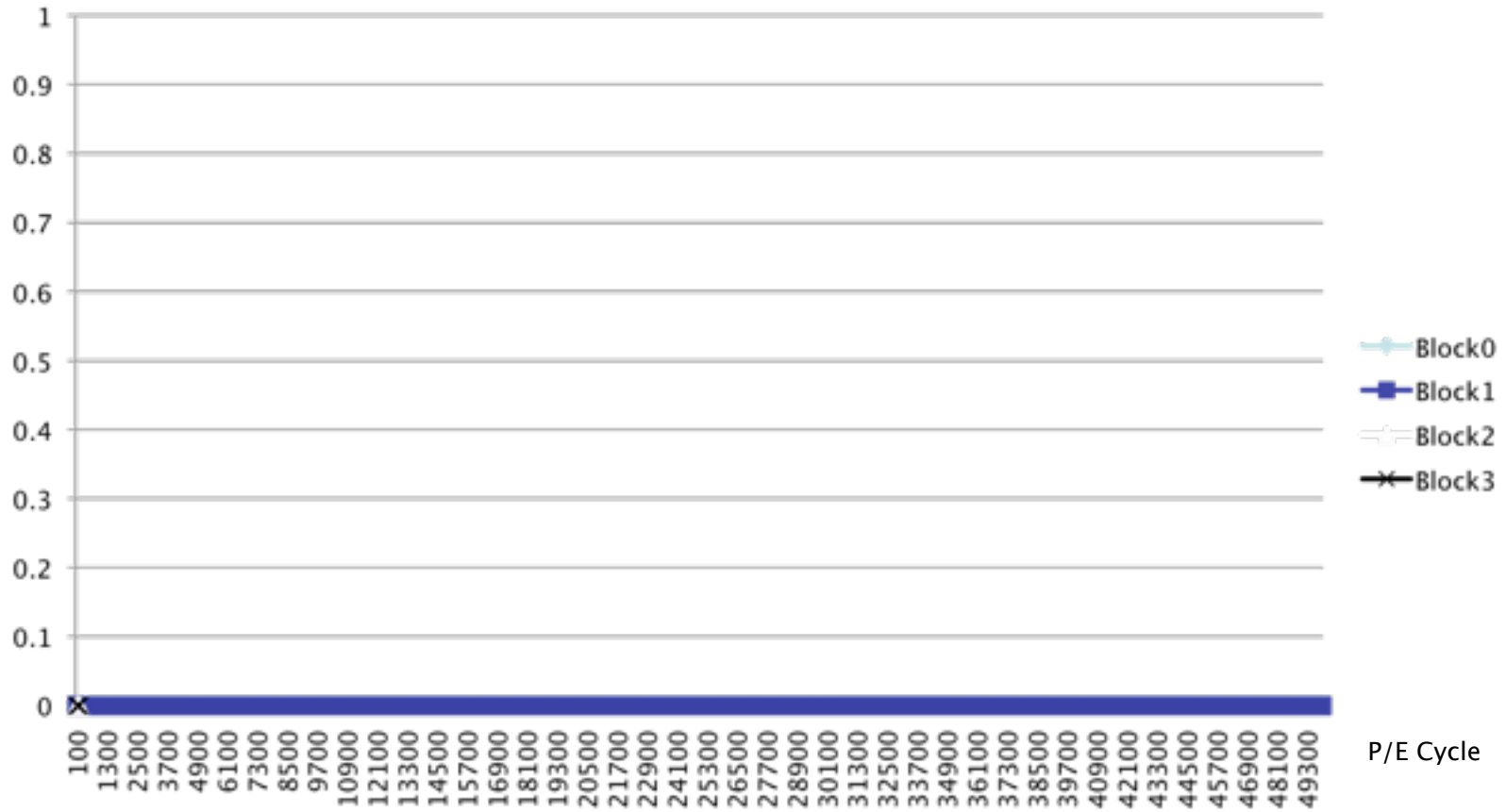


Program Error VS P/E Cycle 3xnm MLC

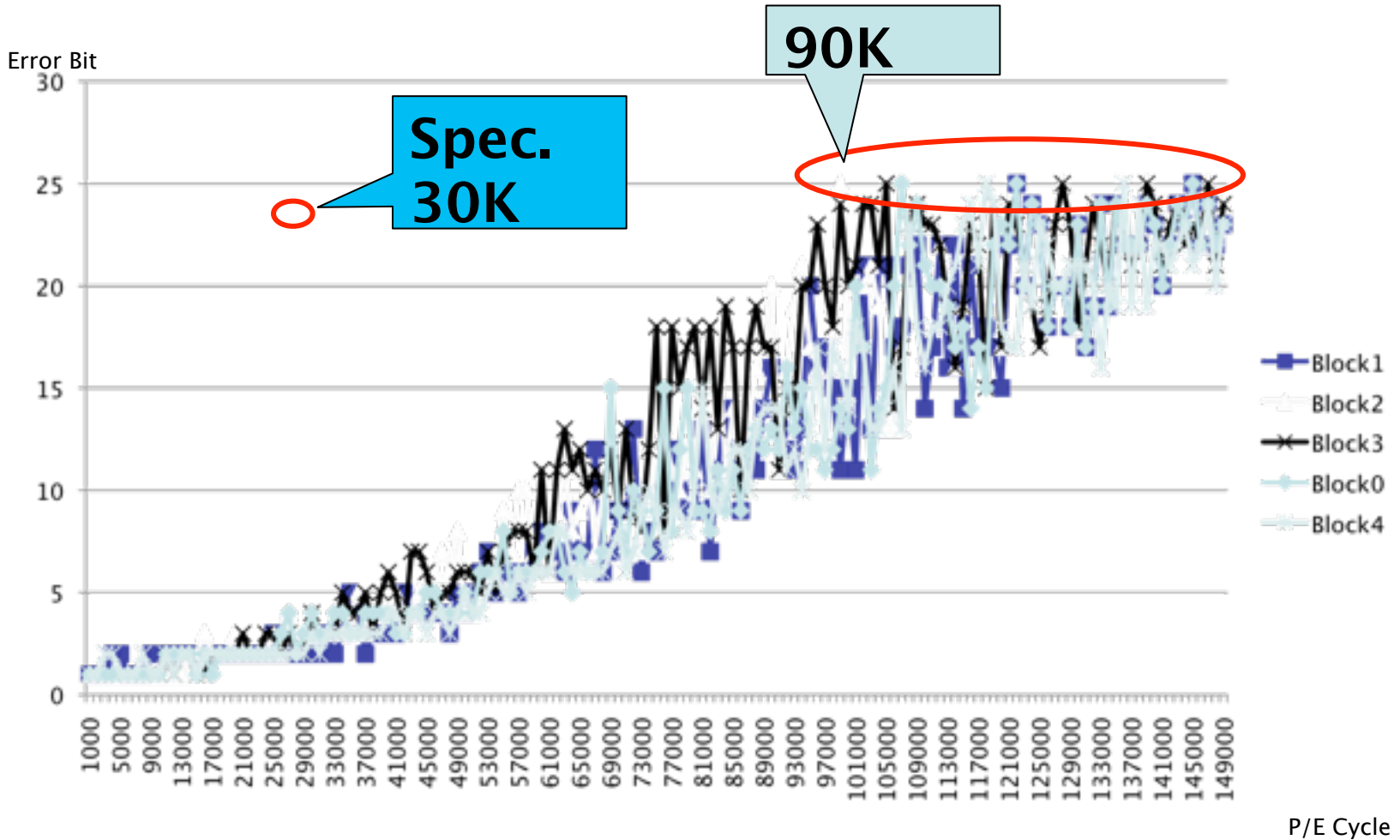




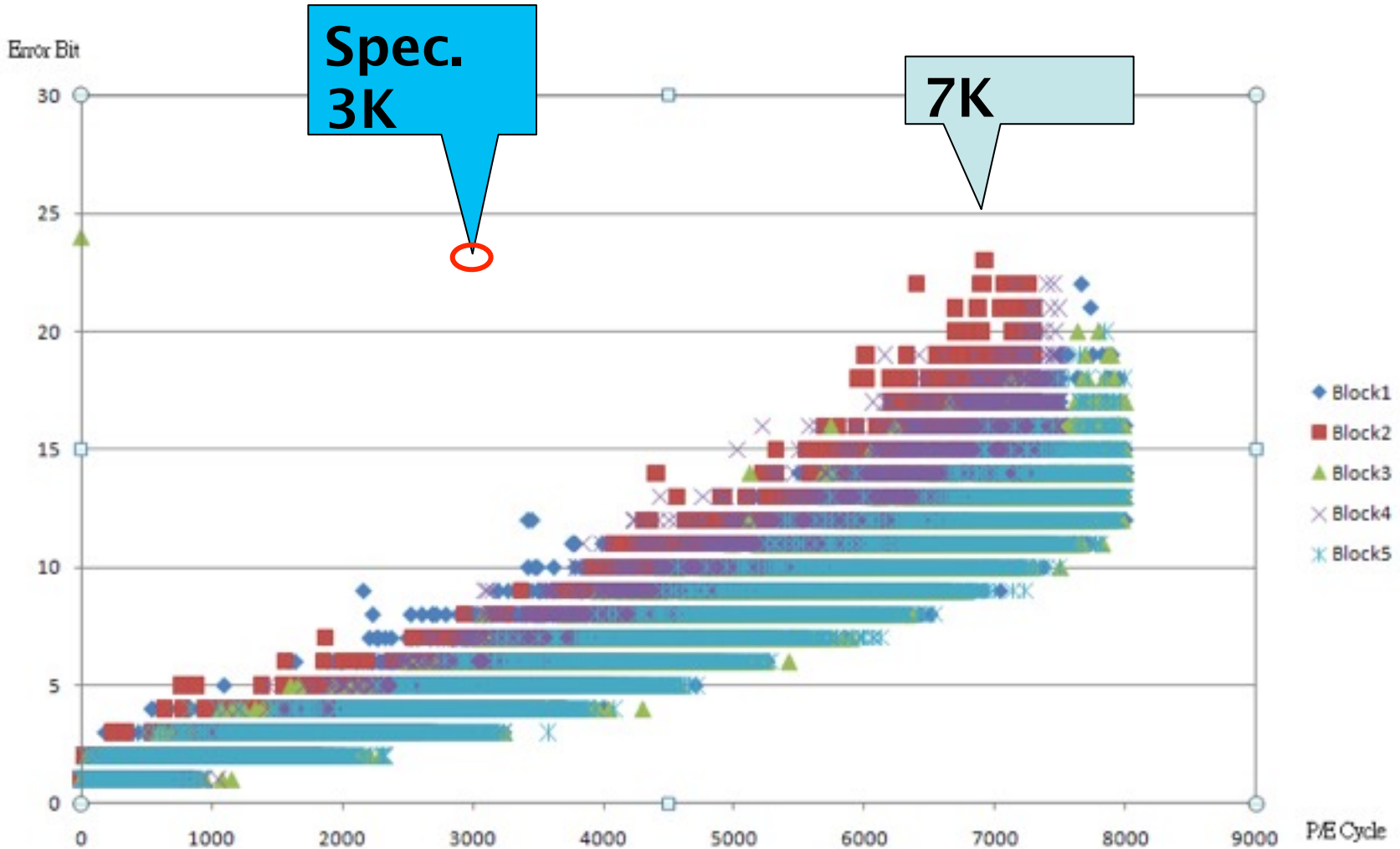
Erase Error VS P/E Cycle 3xnm MLC



Bit Error VS P/E Cycle 3xnm eMLC



Bit Error VS P/E Cycle 2xnm MLC

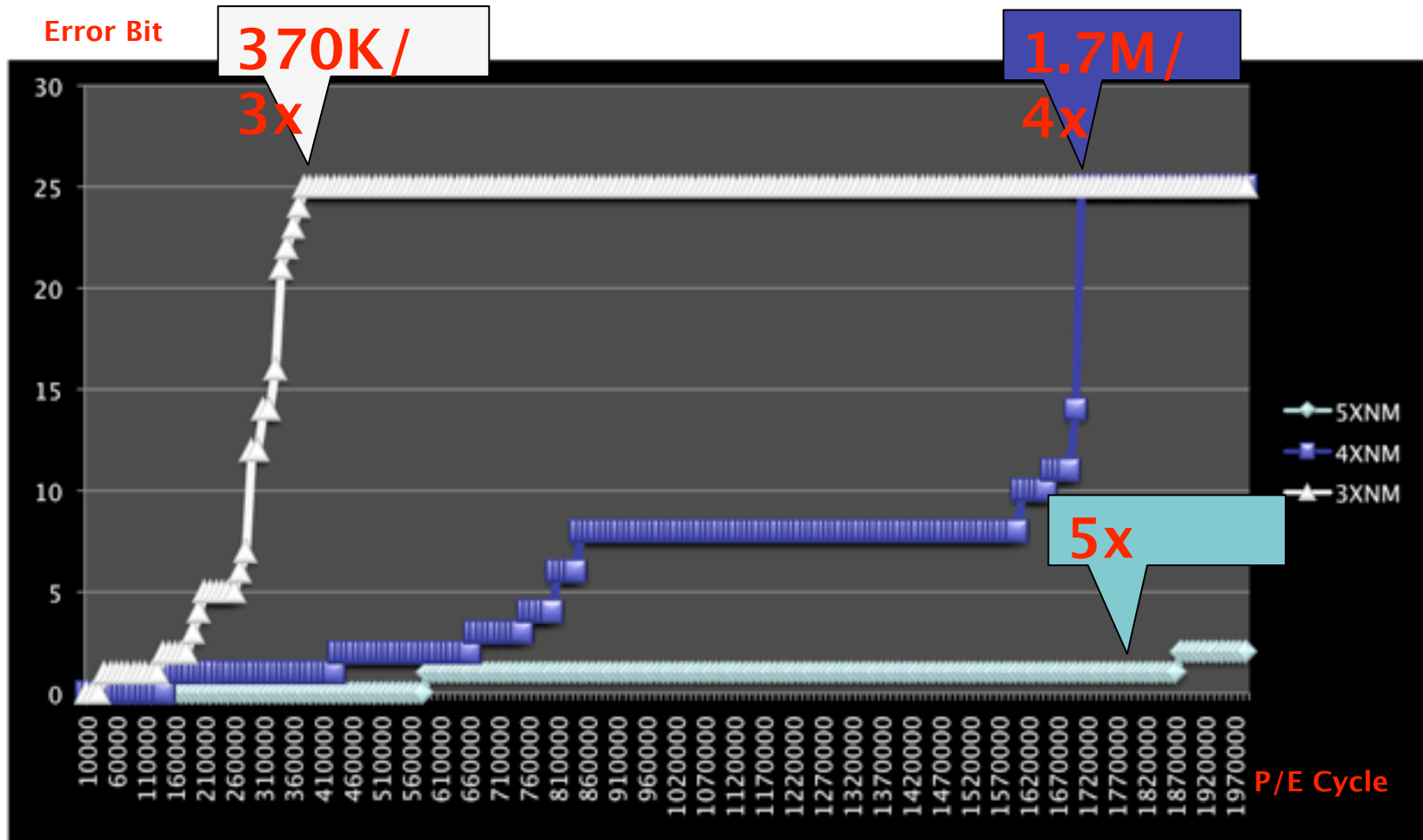




Program/Erase Error VS P/E Cycle

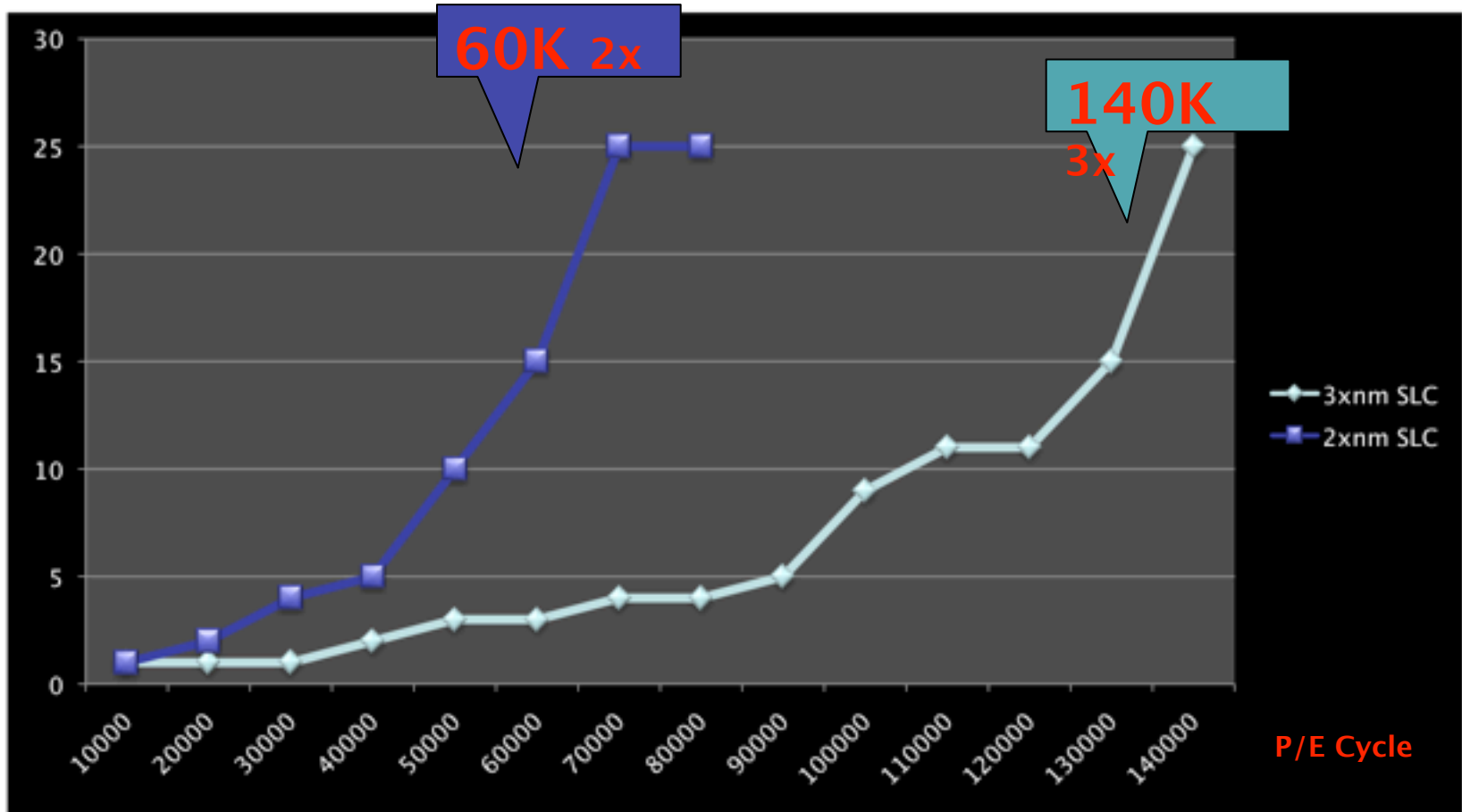
- We get program/erase error with early bad block.
- We got every few program/erase error during testing.

SLC Quality (5x,4x,3x) in different process Brand A

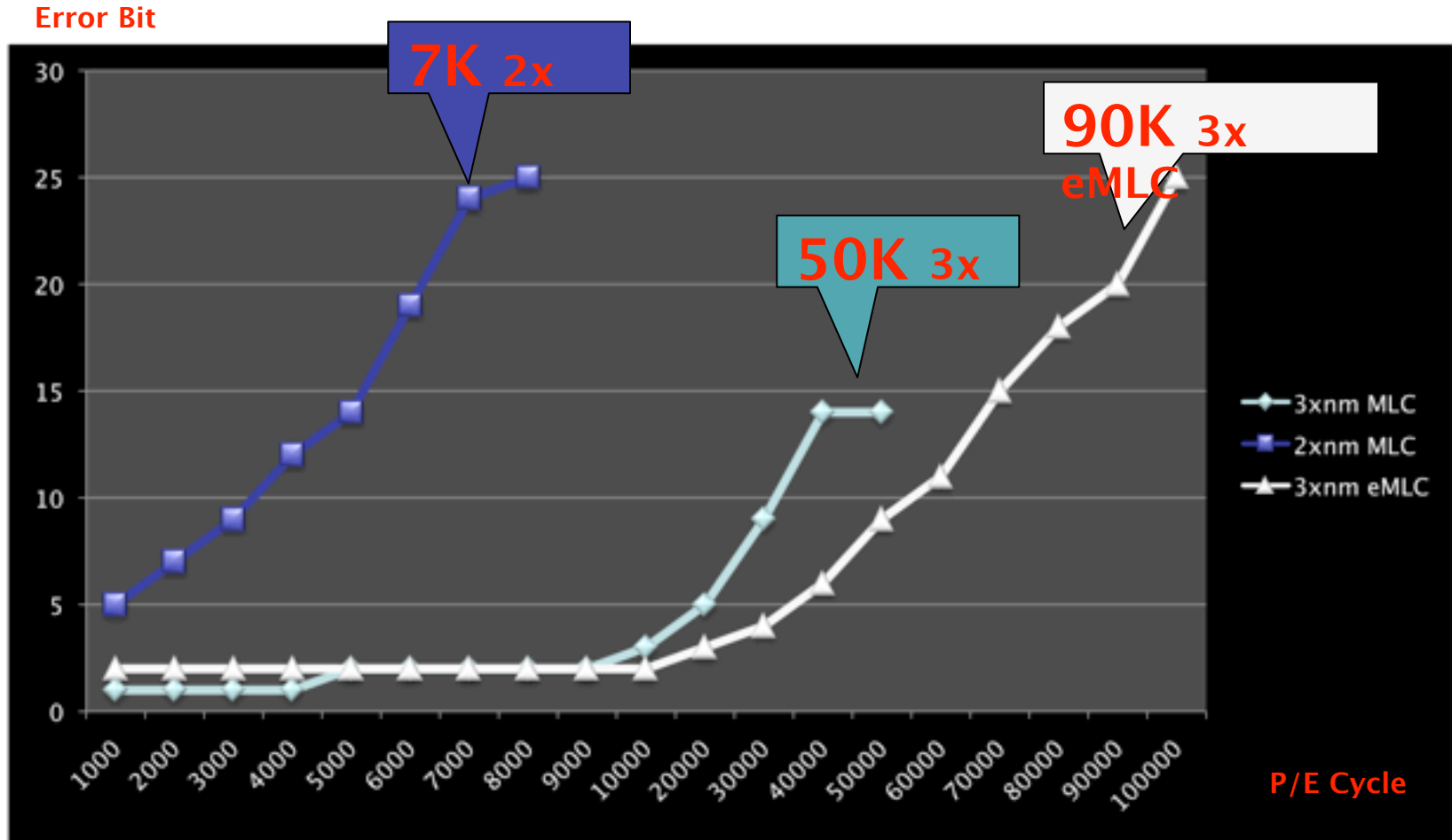


SLC Quality (3x,2x) in different process Brand B

Error Bit



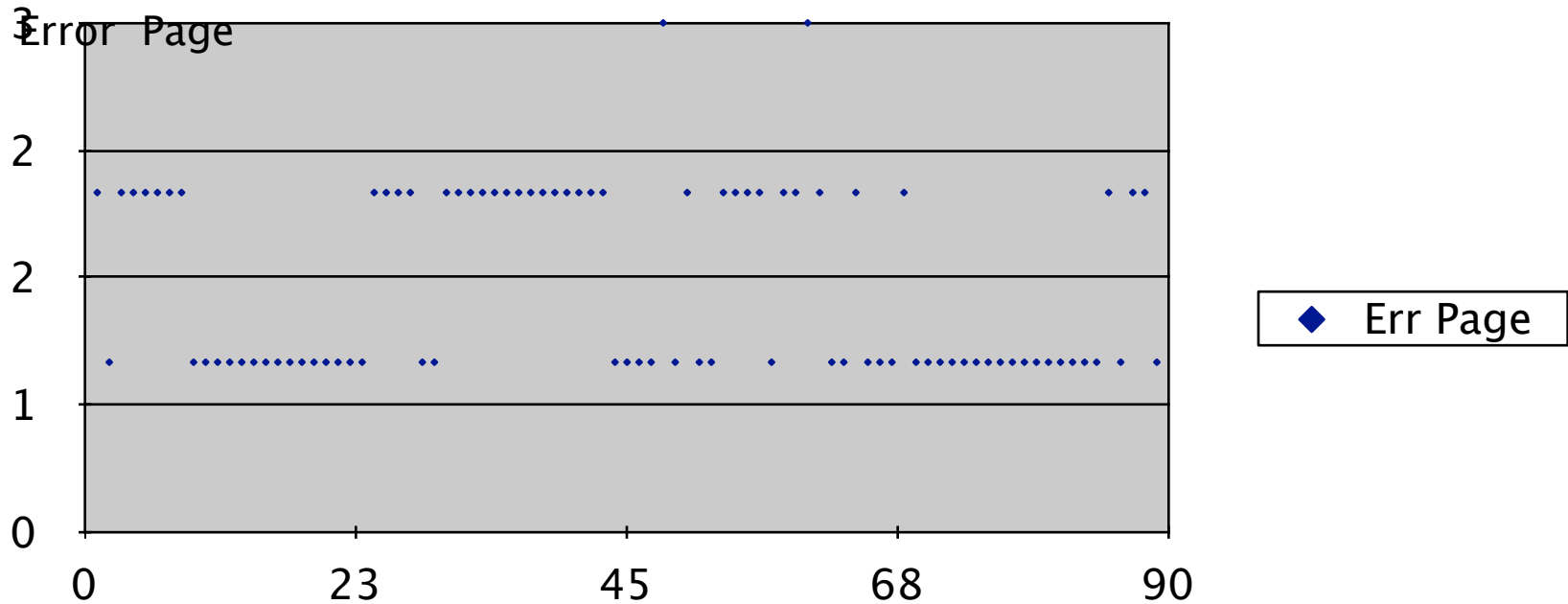
MLC (3x,2x) / eMLC (3x) Quality



Bit Error of Power Cycling

- Cut the power while writing data to SSD
- The flash is MLC

Power Failure Error



Bit Error of Power Cycling

- Pair of page will be corrupted together

	Page1	Page2
1	0x26	0x2C
2	0x6A	0x70
3	0x0B	0x11
4	0x73	0x79
5	0x5B	0x61



Key of SSD's quality

- A good ECC Engine to enhance SSD's P/E Cycle.
- Select a good quality flash chip to extend SSD's lifespan.
- Need a power cycling recover capability to cover MLC's weakness.

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EDC 8000 40pin



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